NSN 5961-01-044-6513

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-044-6513 **Inclosure Material:** Glass **Overall Length:** 0.552 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.680 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 reverse voltage, instantaneous and 106.0 reverse voltage, total rms **Current Rating Per Characteristic:** 30.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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